## 1N4001G THRU 1N4007G



Green Products

Technical Data Data Sheet N0544, Rev. -

## 1N4001G THRU 1N4007G 1.0A GLASS PASSIVATED RECTIFIER

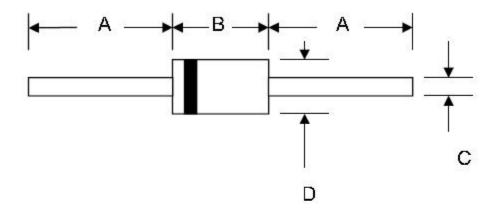
#### Features:

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Mechanical data:

- Case: Molded Plastic
- Terminals: Plated Leads Solderable Per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.35 grams(Approx)
- Mounting Position: Any

### **Mechanical Dimensions: In mm/Inches**



D0-41							
Dim	Min	Max	Min	Max			
Α	25.4	e	1.000				
в	4.06	5.21	0.159	0.205			
С	0.71	0.864	0.028	0.034			
<b>D</b> 2.00	2.00	2.72	0.079	0.107			
	In mm		In inch				

DO-41

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#### Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

#### Where XXXXX is YYWWL

1N4001G	= Part Name
SSG	= SSG
YY	= Year
WW	= Week

= Lot Number

### **Ordering Information**

Device	Package	Shipping
1N4001G-1N4007G	DO-41 (Pb-Free)	5000pcs / tape

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For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

#### Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	1N 4001G	1N 4002G	1N 4003G	1N 4004G	1N 4005G	1N 4006G	1N 4007G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Average forward rectified output current @T <sub>A</sub> = 75°C	lo	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	30							A
Forward Voltage @I <sub>F</sub> =1.0A	V <sub>FM</sub>	1.0						V	
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	I <sub>RM</sub>	5.0 50						μA	
Typical Junction Capacitance (Note 2)	CJ	8						pF	
Typical Thermal Resistance Junction to Ambient (Note 1)	R <sub>θJA</sub>	100						°C/W	
Operating Junction Temperature Range	TJ	-65 to +175						°C	
Storage Temperature Range	T <sub>STG</sub>	-65 to +175						°C	

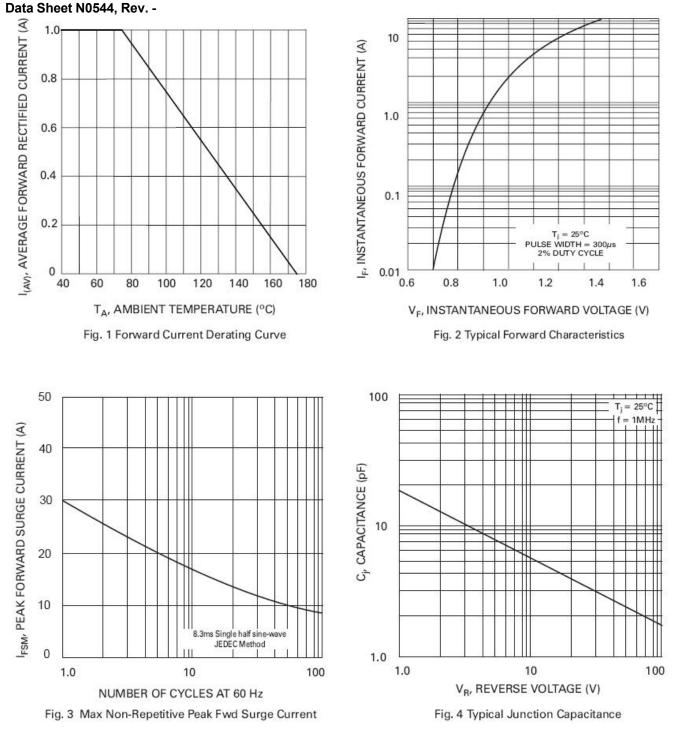
Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm form the case. 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

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